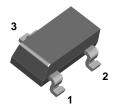
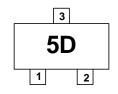
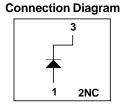


MMBD914







SOT-23

Small Signal Diode

Absolute Maximum Ratings*

T_A = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Maximum Repetitive Reverse Voltage	100	V
I _{F(AV)}	Average Rectified Forward Current	200	mA
I _{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 2.0	A A
T _{stg}	Storage Temperature Range	-55 to +150	°C
TJ	Operating Junction Temperature	150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Units
P _D	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

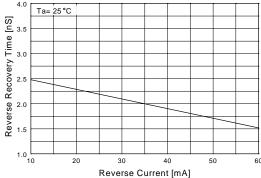
Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
V_R	Breakdown Voltage	$I_R = 5.0 \mu\text{A}$ $I_R = 100 \mu\text{A}$	75 100		V V
V _F	Forward Voltage	I _F = 10 mA		1.0	V
I _R	Reverse Current	V _R = 20 V V _R = 20 V, T _A = 150°C V _R = 75 V		25 50 5.0	nA μA μA
C _T	Total Capacitance	V _R = 0, f = 1.0 MHz		4.0	pF
t _{rr}	Reverse Recovery Time	$I_F = 10 \text{ mA}, V_R = 6.0 \text{V},$ $I_{RR} = 1.0 \text{ mA}, R_L = 100 \Omega$		4.0	ns
V _{FR}	Peak Forward Recovery Voltage	$I_F = 50$ mA PEAK SQUARE WAVE PULSE WIDTH = 0.1 μ S 5 kHz - 100 kHz REP RATE		2.5	V

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Typical Characteristics



Reverse Current [mA]
Figure 7. Reverse Recovery Time
vs Reverse Current
TRR - IR 10 mA vs 60 mA

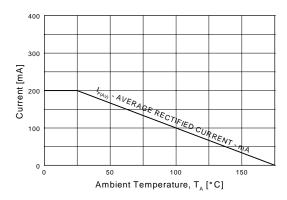


Figure 8. Average Rectified Current ($I_{F(AV)}$) versus Ambient Temperature (T_A)

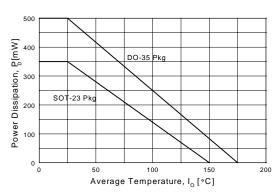


Figure 9. Power Derating Curve

Typical Characteristics

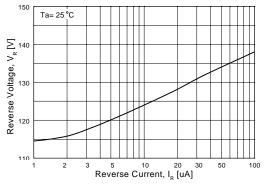


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100uA

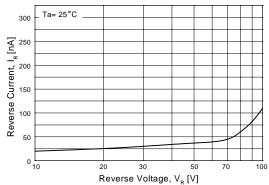


Figure 2. Reverse Current vs Reverse Voltage IR - 10 to 100 V

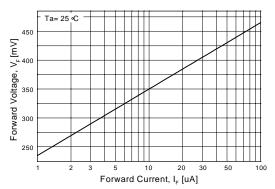


Figure 3. Forward Voltage vs Forward Current VF - 1.0 to 100 uA

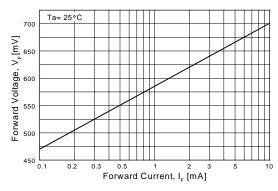


Figure 4. Forward Voltage vs Forward Current VF - 0.1 to 10 mA

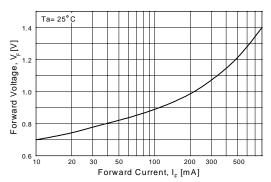


Figure 5. Forward Voltage vs Forward Current VF - 10 - 800 mA

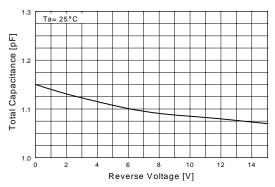


Figure 6. Total Capacitance vs Reverse Voltage

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